the Brillouin zone, we can point out the following unrealistic features of the lattice-dynamical model. The  $\gamma$ 's of all modes are rather closely spaced, and the solid tends towards the limit of a pure Grüneisen solid (i.e., one for which all the  $\gamma_i$  are equal). This explains, of course, the negligible temperature dependence of the calculated Grüneisen parameter. The mode  $\gamma$ 's which are most severely distorted in this model are those corresponding to longitudinal modes. Thus, for long-wave LA phonons propagating in the [100] direction, the model gives

$$\gamma_{l} = -\frac{1}{6} + B_{T} \left( C_{11}' - C_{12}' + C_{44}' \right) / 2 \left( C_{11} - C_{12} + C_{44} \right) ,$$
(4)

whereas the correct value (derived from acousticcontinuum theory) is  $-\frac{1}{6} + B_T C'_{11}/2C_{11}$ , which in

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†On leave from the Soreq Nuclear Research Centre, Yavne, Israel.

<sup>1</sup>J. N. Shapiro and L. Knopoff, Phys. Rev. B <u>1</u>, 3990

general is significantly different from (4). For potassium, for example,  $\gamma_l$ , as calculated from (4), is equal to 1.11, and the correct value of the  $\gamma$  of these longitudinal modes is 1.59.

For the corresponding [100] transverse modes the model yields the correct  $\gamma$ ,

$$V_t = -\frac{1}{6} + B_T C'_{44} / 2C_{44} . \tag{5}$$

We note, finally, that because of the extremely small amount of dispersion and anisotropy which the  $\gamma$ 's of this model exhibit, a simple expression of the form

$$\overline{\gamma} = \frac{1}{3} \left( \gamma_{t} + 2\gamma_{t} \right) \tag{6}$$

already gives a very good estimate of the Grüneisen parameter (as shown in the last column of Table I).

1970.

<sup>2</sup>G. R. Barsch and Z. P. Chang, Phys. Status Solidi <u>19</u>, 139 (1967).

 ${}^{3}$ R. A. Miller and D. E. Schuele, J. Phys. Chem. Solids <u>30</u>, 589 (1969).

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## Valley-Orbit Splitting of Excitons – A Comment\*

G. Ascarelli

Physics Department, Purdue University, Lafayette, Indiana 47907 (Received 1 June 1970)

It is shown that when an indirect exciton is created during an optical absorption, the matrix elements of the exciton Hamiltonian calculated between different degenerate final states of the system are not necessarily zero. This implies that valley-orbit splitting of the states as - signed to the indirect exciton creation may exist.

In a recent paper Shaklee and Nahory<sup>1</sup> point out that on the basis of the translational invariance of the exciton wave function there is no possibility of any valley-orbit splitting of the exciton in the way proposed by Ascarelli.<sup>2</sup> They correctly point out that the existence of a mixing of excitons related to each one of the valleys of a multivalley insulator requires some mechanism to provide the necessary crystal momenta in order to compensate for the different crystal momenta of the individual excitons.

A mechanism that provides the crystal momentum exists in the indirect optical absorption, since not only is an exciton created, but a phonon of the appropriate wave vector is exchanged as well. The wave function describing the system therefore has zero wave vector for the creation of an exciton with zero kinetic energy.

Following Ref. 1,  $H_1$  is defined as the perturba-

tion Hamiltonian describing both the electron-hole interaction and the interaction of the exciton with the appropriate phonon. Then  $H_{ij} = \langle \psi_i^* | H_1 | \psi_j \rangle$ , where  $\psi_i$  and  $\psi_j$  are wave functions describing the existence of an exciton and a phonon, respectively, with momenta  $(\vec{k}_i, -\vec{k}_i)$  and  $(\vec{k}_j, -\vec{k}_j)$ . Applying the translation operator T to  $H_1$ , we obtain

$$H_{ij} = \left\langle \psi_i^* \right| \quad T^{-1} T H_1 \left| \psi_j \right\rangle = e^{i (\vec{K}_i - \vec{K}_j) \cdot \vec{a}} H_{ij} .$$

 $H_{ij}$  is therefore not necessarily zero, since the wave vectors  $\vec{K}_i$  and  $\vec{K}_j$  of both  $\psi_i$  and  $\psi_j$  are zero.

The emission of electromagnetic radiation during the annihilation of an exciton may give rise to valley-orbit splitting in the same way as absorption does, since the same arguments used above remain valid.

The magnitude of the valley-orbit splitting will

depend on the distortion of the lattice in the vicinity of the exciton (providing a sort of central-cell correction) that arises from the interaction of the carriers with their polarization. One therefore expects that the splitting will be larger in ionic crystals that have a strong polaron interaction than in covalent semiconductors, where the electronphonon interaction is provided by means of the deformation potential.

Indeed, while the stress-induced splitting of the different exciton peaks is the same in Si,<sup>1</sup> it is

\*Work supported in part by the National Science Foundation.

<sup>1</sup>K. L. Shaklee and R. E. Nahory, Phys. Rev. Letters 24, 942 (1970).

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## Thermoelectric Power of Cu<sub>3</sub>Au as a Function of Short-Range Order\*

sions.

Kang-Pei Wang<sup>†</sup> and H. Amar

Department of Physics, Temple University, Philadelphia, Pennsylvania 19122 (Received 20 May 1970)

A theoretical study of the diffusion thermoelectric power of Cu<sub>3</sub>Au as a function of order above the critical temperature is made. This work is based on, and completes, our investigation on the residual resistivity of Cu-Au alloys above the critical temperature.

The diffusion thermoelectric power  $Q_D$  has been a subject of both experimental and theoretical investigation for a long time. Nevertheless, there has been practically no theoretical work done towards the study of the order dependence of  $Q_p$  of alloys. In this paper, we propose a pseudopotential theory of  $Q_p$  of binary alloys as a function of short-range order (SRO) and apply our formulation to Cu<sub>3</sub>Au for which the reliable SRO parameters are available.<sup>1</sup>

Consider a disordered binary alloy with a total of N atoms of which  $N_A$  and  $N_B$  are of types A and B, respectively. Assume that these atoms are placed on a rigid Bravais lattice consisting of N sites. Further, postulate that the (pseudo)potential of the system can be written as a sum of the screened ionic pseudopotentials of types A and B, i.e.,

$$W(\vec{\mathbf{r}}) = \sum_{i} \partial_{i}^{A} w_{A}(\vec{\mathbf{r}} - \vec{\mathbf{r}}_{i}) + \sum_{i} \partial_{i}^{B} w_{B}(\vec{\mathbf{r}} - \vec{\mathbf{r}}_{i}), \quad (1)$$

where the occupation operators<sup>2</sup>  $\partial_i^{\lambda}$  are defined as follows:

- $\partial_i^{\lambda} = 1$  if the *i*th lattice site is occupied by an atom of type  $\lambda$ 
  - = 0 otherwise

and  $\omega_{\lambda}$  is the screened ionic pseudopotential of type λ.

different in the peaks assigned to the valley-orbit-

states in the absence of the electron-phonon inter-

justified in the description of the creation of ex-

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citons by means of indirect optical transitions.

action,<sup>3</sup> the neglect of the latter is not, in principle,

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<sup>2</sup>G. Ascarelli, Phys. Rev. Letters 20, 44 (1968); Phys.

<sup>3</sup>P. J. Dean, Y. Yafet, and J. R. Haynes, Phys. Rev B

1, 4193(E) (1970); Y. Yafet (private communication).

In conclusion, it is pointed out that although there is no valley-orbit splitting of related indirect exciton

split exciton in AgBr.<sup>2</sup>

Rev. 179, 797 (1969).

For such a system, we have in a previous paper<sup>3</sup> been able to express the resistivity as a function of SRO as follows:

$$\rho(E) = \frac{3\pi m \Omega_0}{8\hbar e^2 E} \int_0^2 \left| \frac{q}{K} \langle \vec{\mathbf{k}} + \vec{\mathbf{q}} \right| w_A - w_B \left| \vec{\mathbf{k}} \right\rangle \right|^2 \times m_A m_B \frac{q}{K} \sum_i \alpha_i C_i j(n_i q) d\left(\frac{q}{K}\right) , \qquad (2)$$

where  $\Omega_0$  is the atomic volume per ion,  $m_{\lambda} = N_{\lambda}/N$ , and E is the energy of an electron in the plane-wave state  $|K\rangle$ . The integrand appearing in Eq. (2) consists of two factors: the "atomic part," which is proportional to the square of the difference of the form factors of A and B atoms, i.e.,  $|\langle \vec{k} + \vec{q} | w_A | \vec{k} \rangle$  $-\langle \vec{\mathbf{k}} + \vec{\mathbf{q}} | w_B | \vec{\mathbf{k}} \rangle |^2$ , and the "structural part," which is a function of short-range order parameters  $\alpha_i$ , the coordination number of the *i*th shell  $c_i$ , and the vectors  $n_i$  locating the atoms in the *i*th shell.

The diffusion thermoelectric power in units of  $\pi^2 k_B^2 \tau / 3eE$  can be written as<sup>4</sup>

$$Q_D = -E_F \left(\frac{\partial \ln \rho(E)}{\partial E}\right)_{E=E_F} .$$
(3)